

# **Visible Electroluminescence from silicon nano-crystals embedded in amorphous silicon nitride matrix**

Applied Physics Letters, 2005

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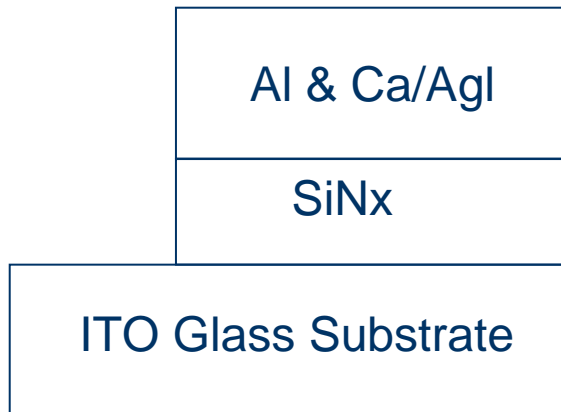
# OUTLINE

- INTRODUCTION
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- RESULTS
  - PL
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  - EL
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- CONCLUSION

# INTRODUCTION

- Nc-Si embedded in a SiO<sub>x</sub> matrix have been demonstrated to emit visible light by photoluminescence measurements. But only a few papers have reported on the electroluminescence
- In this study, they are using SiN<sub>x</sub> as matrix rather than SiO<sub>x</sub>.

# EXPERIMENTS

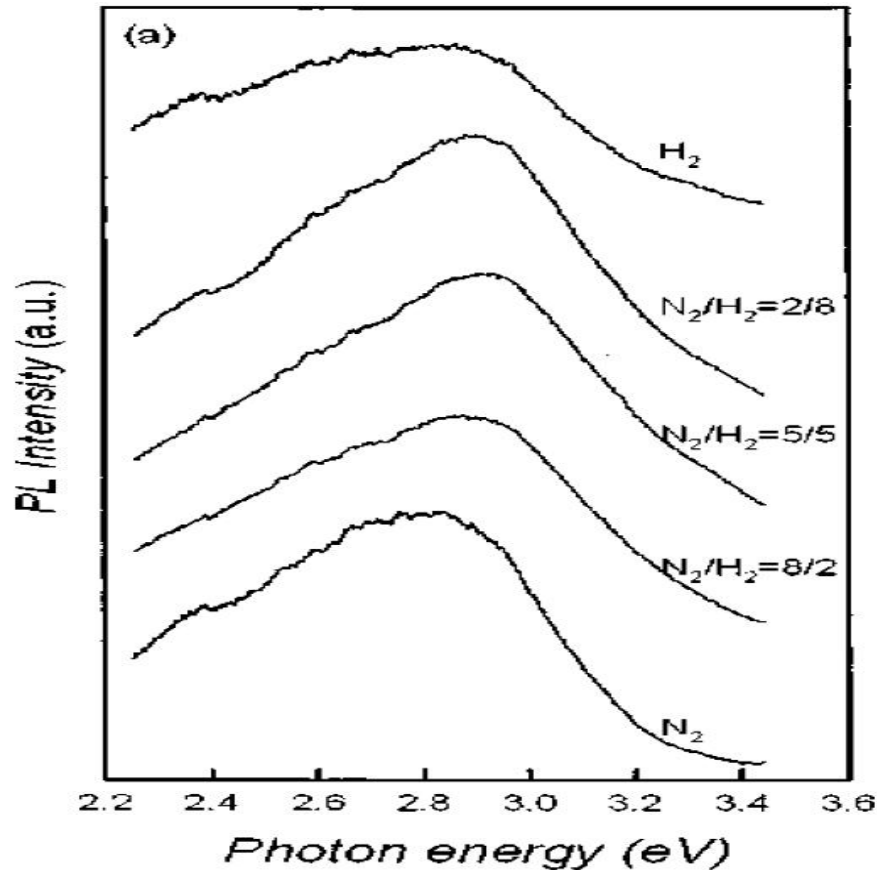


Substrate : ITO Glass &  
Si(100)

Prepare : using e-beam  
evaporation of Si into the  
inductively coupled plasma  
(ICP)

Gas :  $N_2$  and  $H_2$

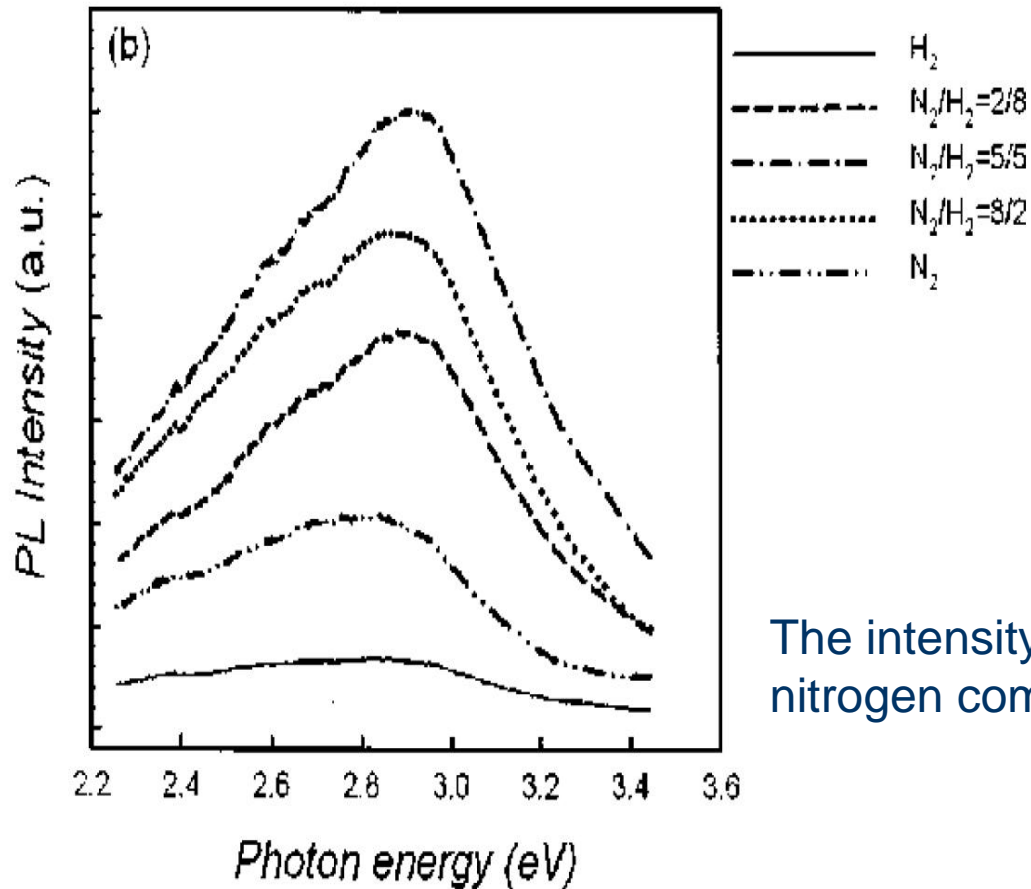
# RESULT OF PL MEATSURMENT



A Xe lamp operated at 150w was employed as the excitation source for the PL spectra, and the wave length of excitation is 325nm.

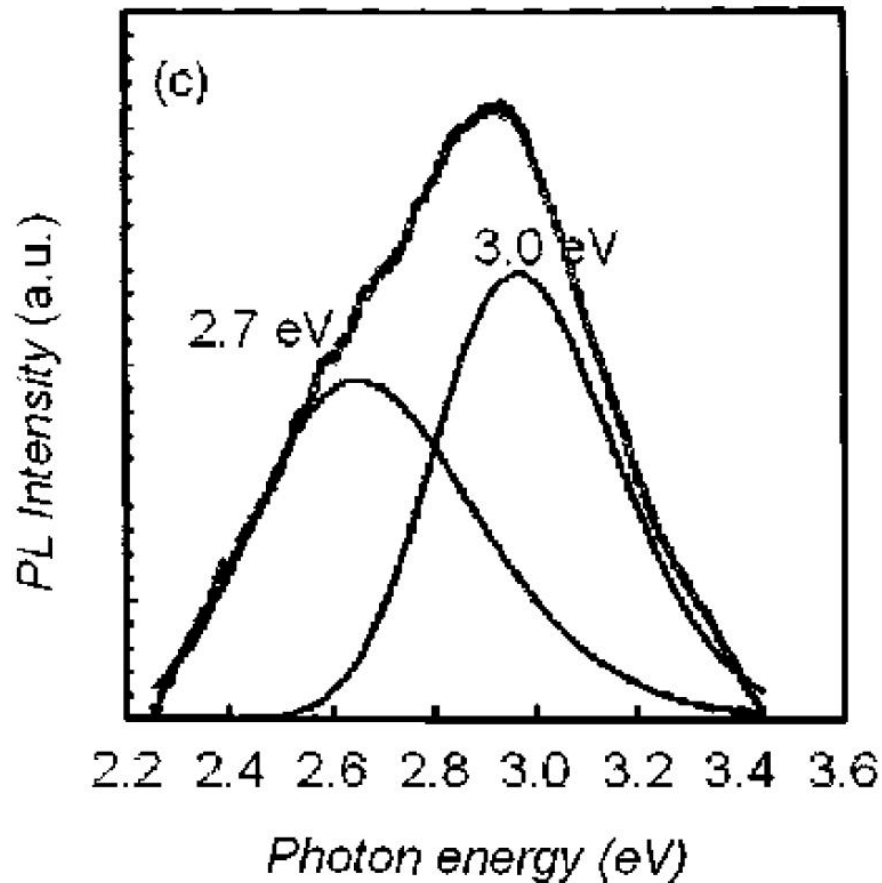
PL spectra of the films deposited at various  $N_2/H_2$  ratios.

# RESULT OF PL MEASUREMENT



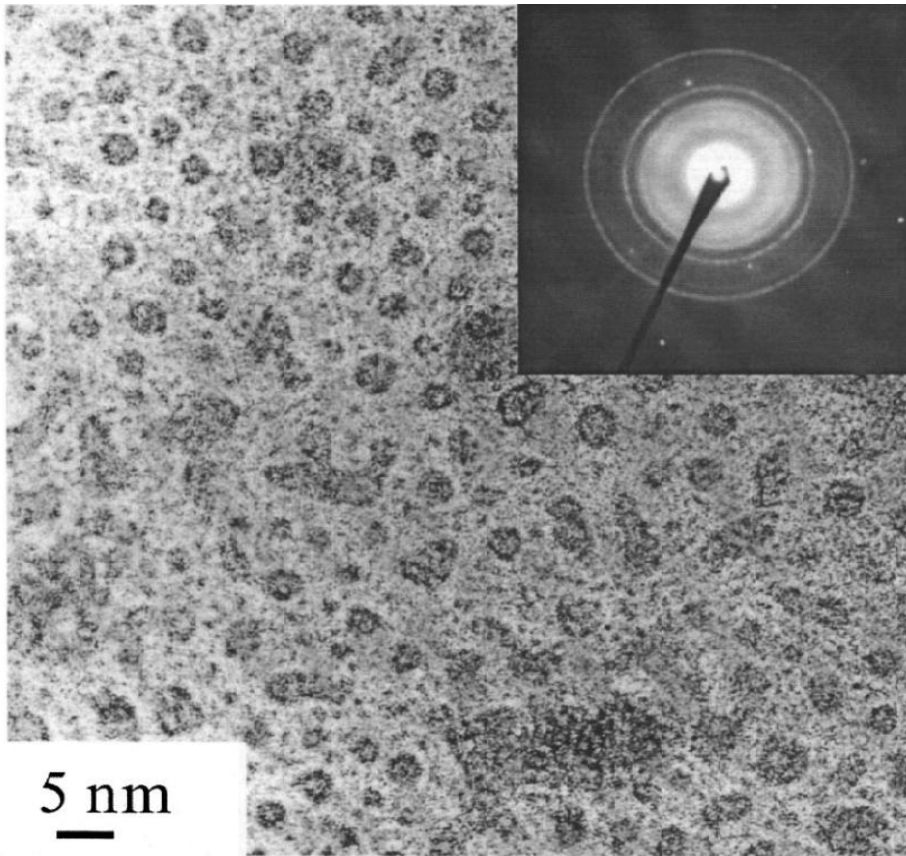
The intensity of PL as a function of nitrogen composition in the gas.

# RESULT OF PL MEASUREMENT



The deconvolution of PL spectra at N<sub>2</sub>/H<sub>2</sub>=5:5 into two peaks 2.7 and 3.0 eV.

# RESULT OF TEM

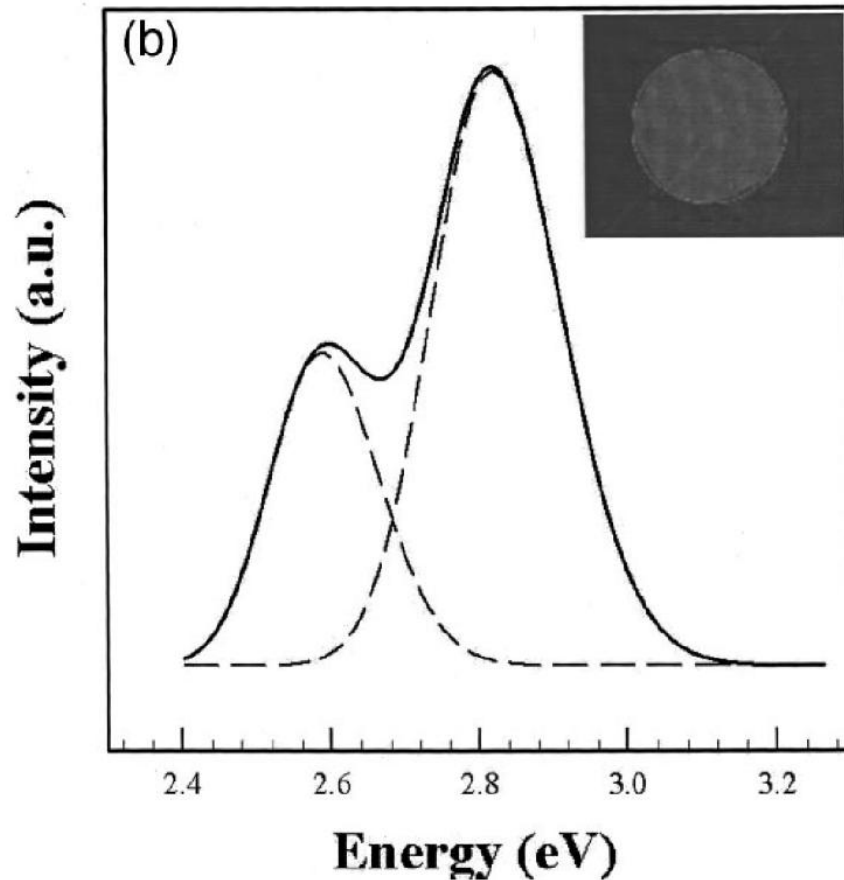


The sizes of nc-Si were in the range of 1-5nm, and the density of nc-Si was about  $5 \times 10^{12} \text{cm}^{-2}$ .

HRAEM image of the nc-Si/a-SiNx nanocomposite. The inset shows a selective area diffraction pattern of Si nanocrystals.

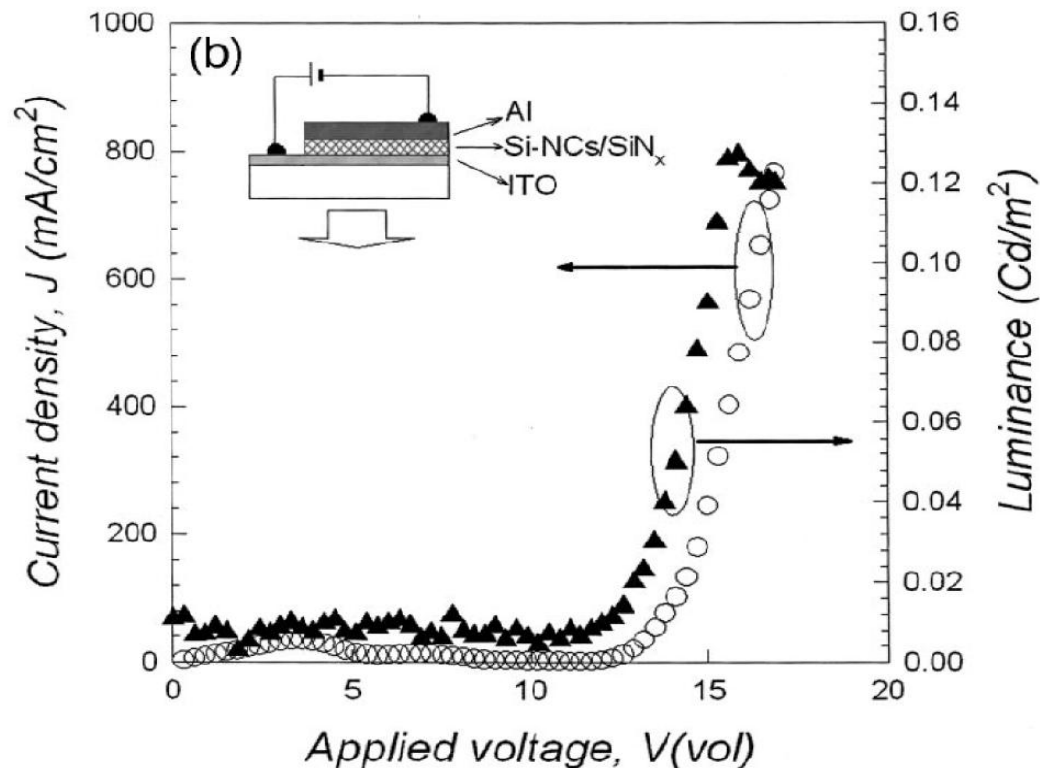


# RESULT OF EL MEASUREMENT



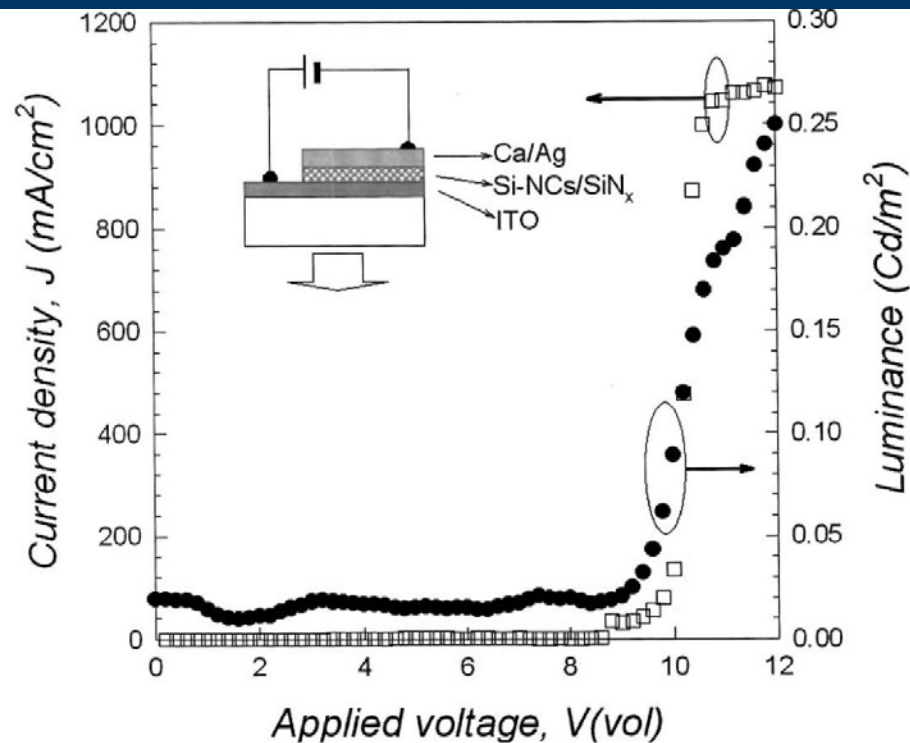
The photograph of EL device emission. The diameter of the pattern is about 2mm

# RESULT OF I-V MEATSURMENT



The characteristics of the current density and the luminance versus the forward bias voltage for the nc-Si/a-SiN<sub>x</sub> film with the the Al cathode measured at room temperature.

# RESULT OF I-V MEATSURMENT



The characteristics of the current density and the luminance versus the forward bias voltage for the nc-Si/a-SiN<sub>x</sub> film with the Ca/Ag cathode measured at room temperature.

# CONCLUSION

- In this study, the main peak of photoluminescence spectra is a **blue band**.
- For the EL device using **ITO**, **a-SiNx** and **Ca/Ag** as the **anode**, **active layer**, and **cathode**, respectively, the emission was observable with the naked eye through the ITO glass in the dark.